

BCR2AS-14A

700V - 2A - Triac

Low Power Use

R07DS0257EJ0101

Rev.1.01

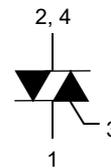
May. 10, 2019

Features

- $I_{T(RMS)}$: 2 A
- V_{DRM} : 700 V
- I_{FGTI} , I_{RGTI} , I_{RGTIII} : 10 mA
- T_j : 125 °C
- Planar Passivation Type

Outline

RENESAS Package code: PRSS0004ZG-A
(Package name: MP-3A)



1. T₁ Terminal
2. T₂ Terminal
3. Gate Terminal
4. T₂ Terminal

Application

Small motor control, heater control, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		14	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	700	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	840	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	2	A	Commercial frequency, sine full wave 360°conduction, $T_c = 112^{\circ}\text{C}$ ^{Note3}
Surge on-state current	I_{TSM}	9	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	0.41	A ² s	Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	1	W	
Average gate power dissipation	$P_{G(AV)}$	0.1	W	
Peak gate voltage	V_{GM}	6	V	
Peak gate current	I_{GM}	1	A	
Junction Temperature	T_j	-40 to +125	°C	
Storage temperature	T_{stg}	-40 to +125	°C	

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak off-state current	I_{DRM}	—	—	1.0	mA	$T_j = 125^\circ\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	2.1	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 3\text{ A}$, instantaneous measurement
Gate trigger voltage ^{Note2}	I	V_{FGTI}	—	—	2.0	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	V_{RGTI}	—	—	2.0	
	III	V_{RGTIII}	—	—	2.0	
Gate trigger current ^{Note2}	I	I_{FGTI}	—	—	10	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II	I_{RGTI}	—	—	10	
	III	I_{RGTIII}	—	—	10	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	4.0	$^\circ\text{C/W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutating voltage ^{Note4}	$(dv/dt)_c$	0.5	—	—	$\text{V}/\mu\text{s}$	$T_j = 125^\circ\text{C}$

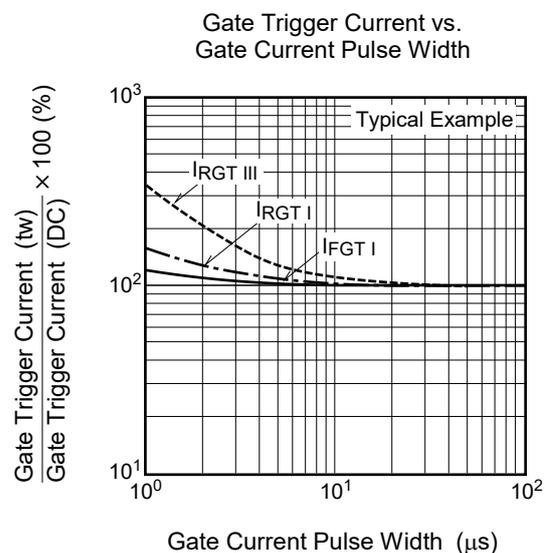
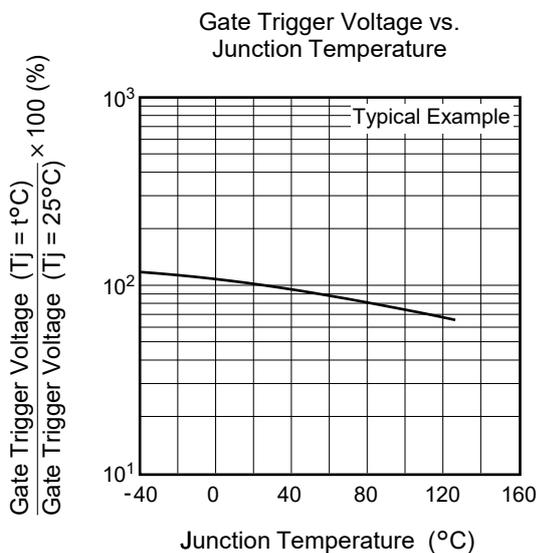
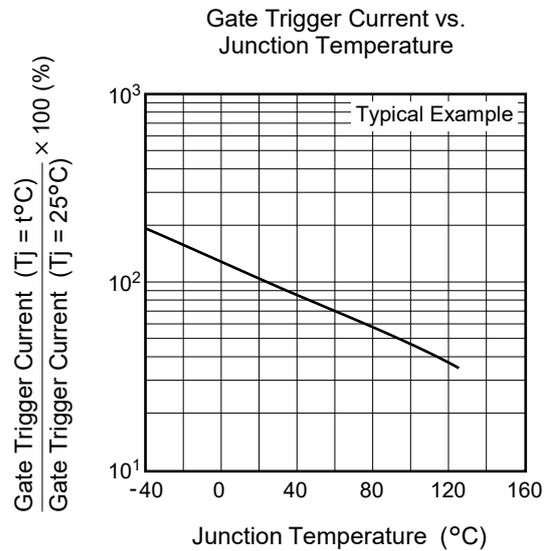
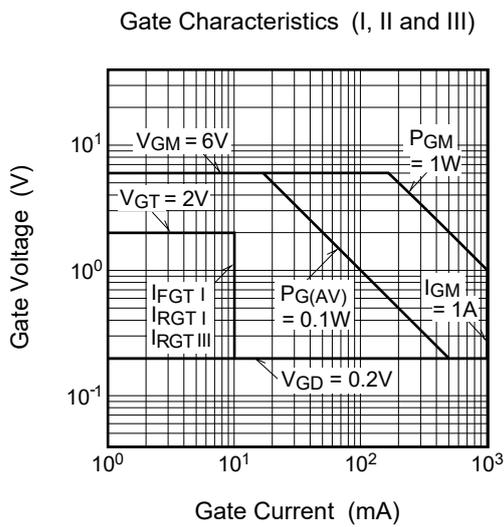
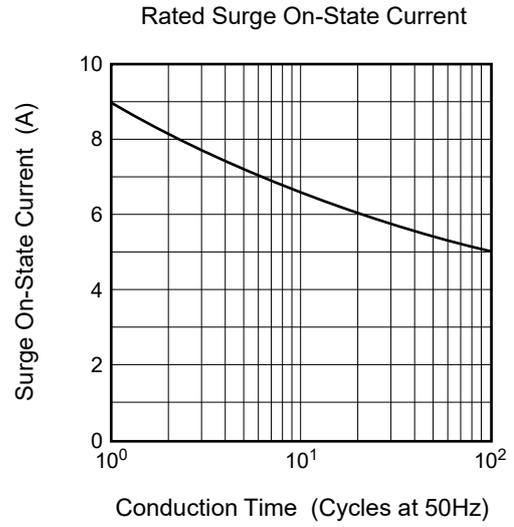
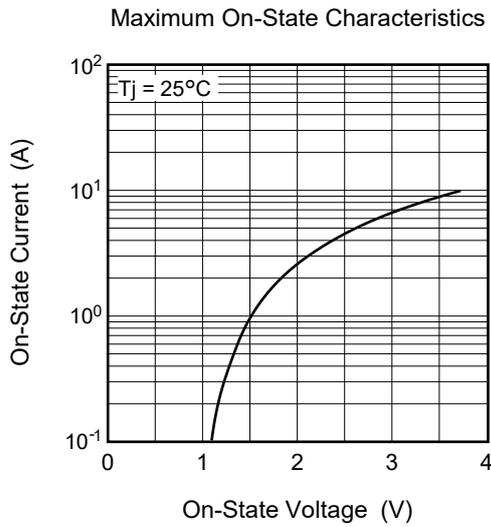
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

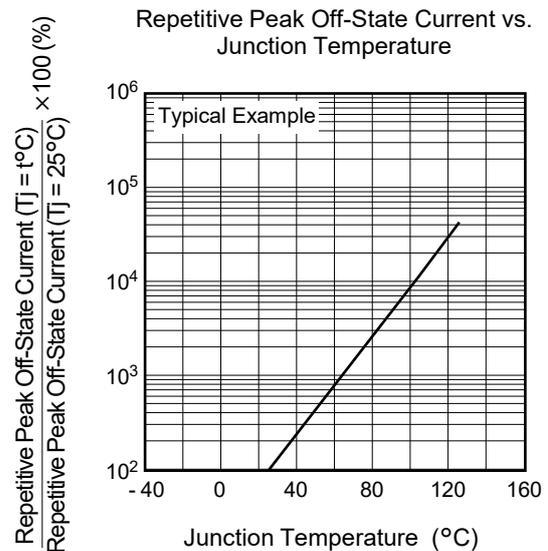
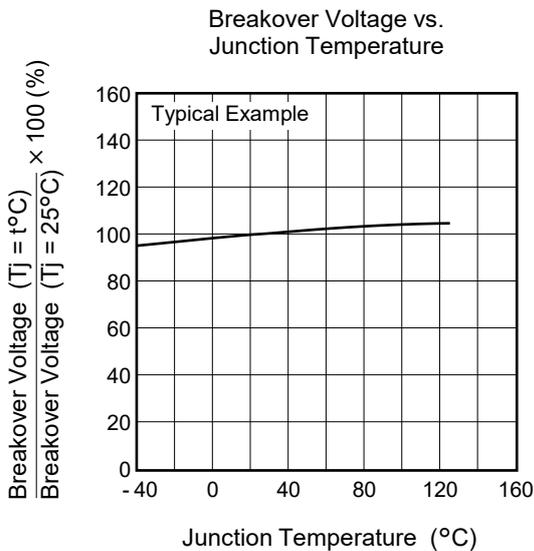
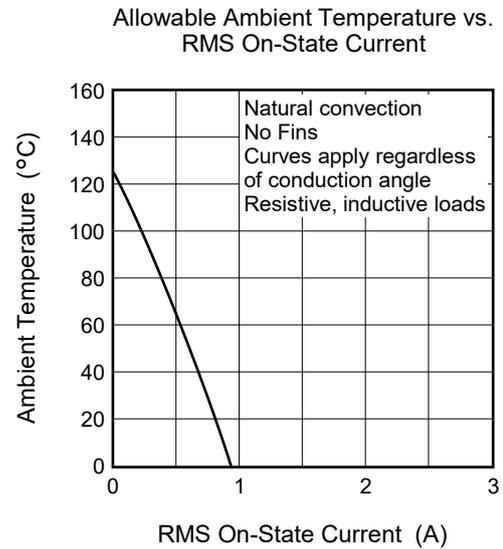
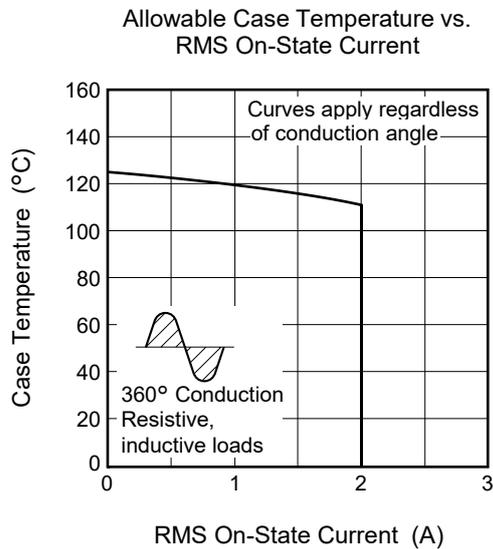
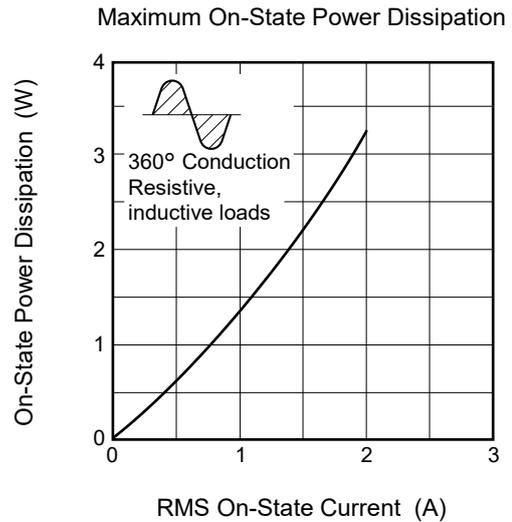
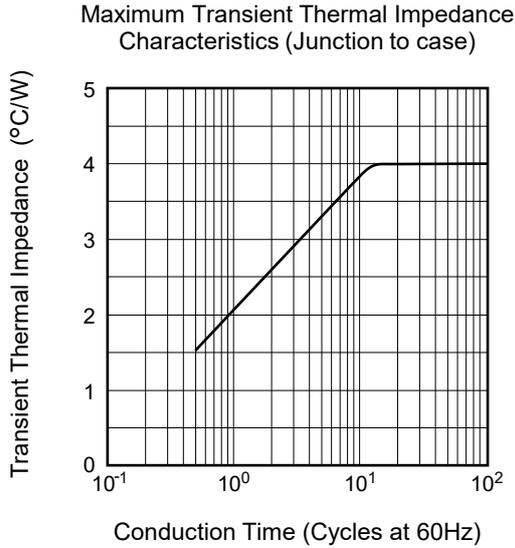
3. Case temperature is measured on the T_2 tab.

4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

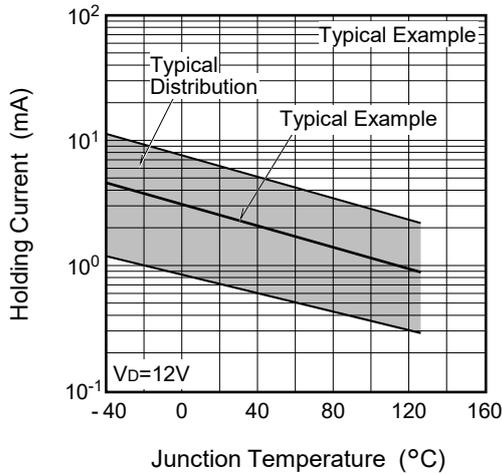
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j = 125^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -1.0\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

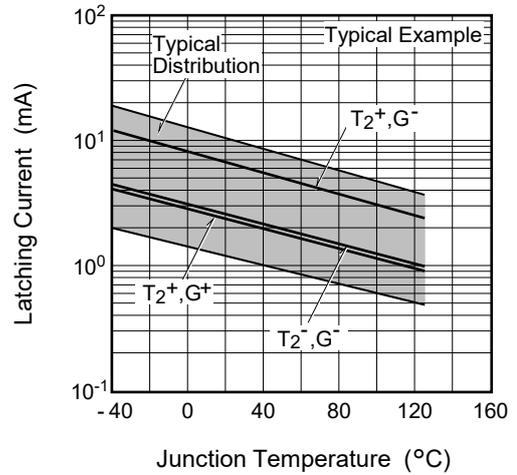




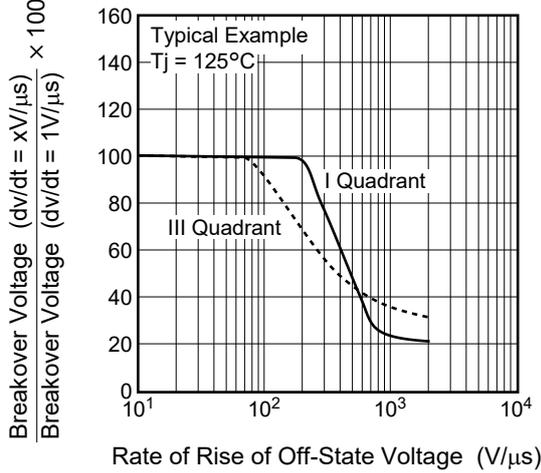
Holding Current vs. Junction Temperature



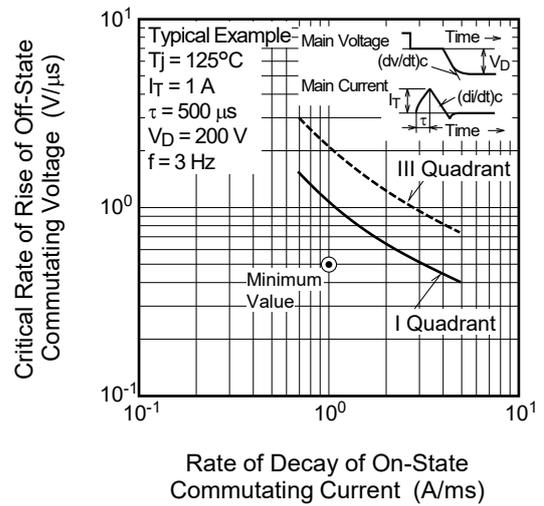
Latching Current vs. Junction Temperature



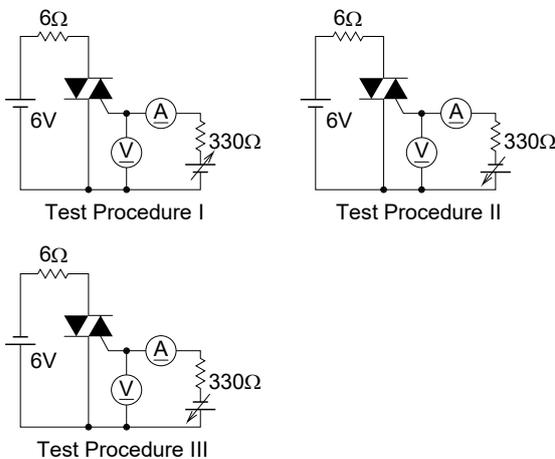
Breakover Voltage vs. Rate of Rise of Off-State Voltage (Tj=125°C)



Commutation Characteristics (Tj=125°C)

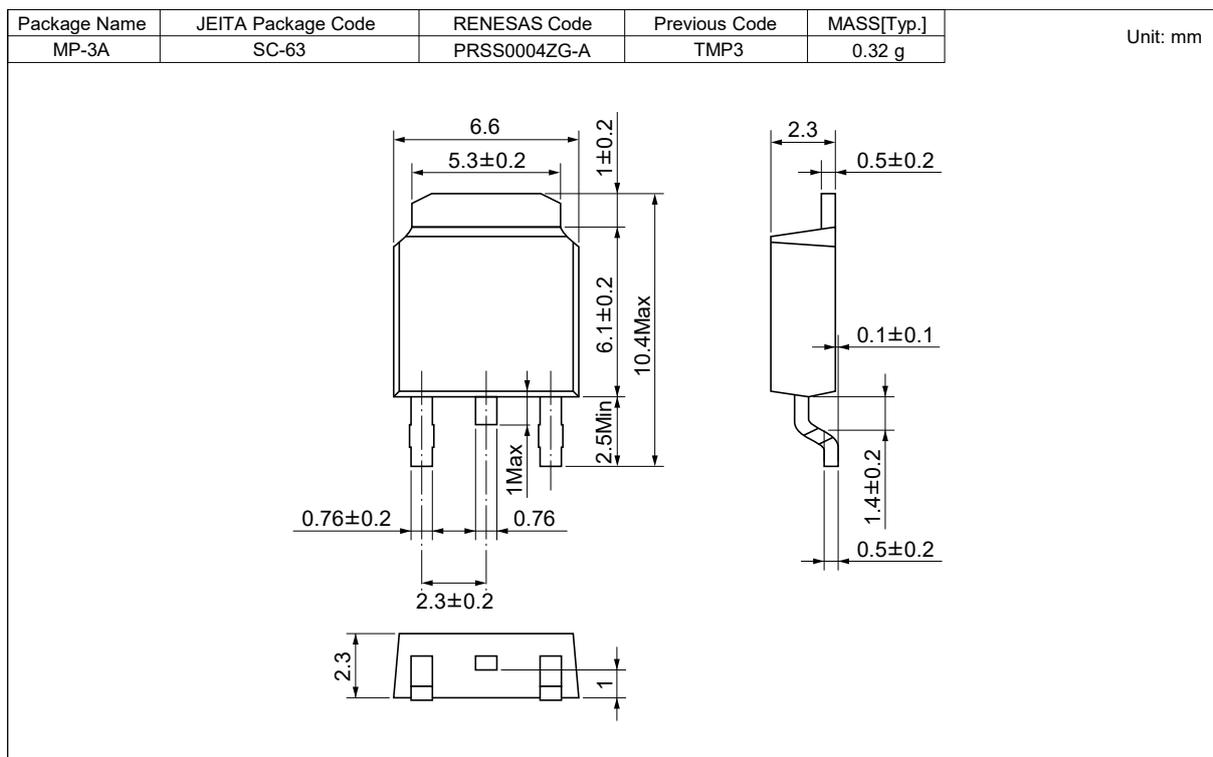


Gate Trigger Characteristics Test Circuits



Package Dimensions

Package Name: MP-3A



Ordering Information

Orderable Part Number	Package	Packing ^{Note5}	Quantity	Remark
BCR2AS-14A-T13#B00	MP-3A	Embossed tape	3000 pcs.	
BCR2AS-14A#B00	MP-3A	Tube	75 pcs.	Tube packing is to be abolished.

Note: 5. Please confirm the specification about the shipping in detail.